

## **IXFK50N85X Datasheet**



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DiGi Electronics Part Number IXFK50N85X-DG

Manufacturer IXYS

Manufacturer Product Number IXFK50N85X

Description MOSFET N-CH 850V 50A TO264

Detailed Description N-Channel 850 V 50A (Tc) 890W (Tc) Through Hole

TO-264AA



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DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFK50N85X	IXYS
Series:	Product Status:
HiPerFET™, Ultra X	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
850 V	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	105mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 4mA	152 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	4480 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	890W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-264AA	TO-264-3, TO-264AA
Base Product Number:	
IXFK50	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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